

# **Current Transducer HO-P/SP33 series**

 $I_{\rm PN}$  = 60, 100, 120, 180, 250 A

Ref: HO 60-P/SP33, HO 100-P/SP33, HO 120-P/SP33, HO 180-P/SP33, HO 250-P/SP33

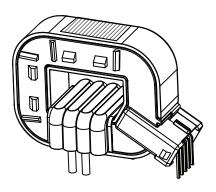
For the electronic measurement of current: DC, AC, pulsed..., with galvanic separation between the primary and the secondary circuit.











#### **Features**

- · Open loop multi-range current transducer
- Voltage output
- Overcurrent detect 2.92 × I<sub>PN</sub> (peak value)
- EEPROM Control
- Galvanic separation between primary and secondary circuit
- Low power consumption
- · Compact design for THT PCB mounting
- Aperture: 15 × 8 mm
- · Factory calibrated
- · Dedicated parameter settings available on request (see page 11).

#### **Special feature**

• Single power supply +3.3 V.

#### **Advantages**

- Low offset drift
- Over-drivable V<sub>ref</sub>
- 8 mm creepage/clearance
- · Fast response.

### **Applications**

- AC variable speed and servo motor drives
- · Static converters for DC motor drives
- · Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications
- Combiner box
- MPPT.

#### **Standards**

- IEC 61800-1: 1997
- IEC 61800-2: 2015
- IEC 61800-3: 2004
- IEC 61800-5-1: 2007
- IEC 62109-1: 2010
- UL 508: 2013.

#### **Application Domain**

• Industrial.

N°97.K4.27.Q36.0; N°97.K4.34.Q36.0; N°97.K4.36.Q36.0; N°97.K4.42.Q36.0, N°97.K4.45.Q36.0

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#### **Absolute maximum ratings**

Parameter	Symbol	Unit	Value
Supply voltage (not destructive)	$U_{\rm c}$	V	8
Supply voltage (not entering non standard modes)	$U_{\rm c}$	V	6.5
Primary conductor temperature	$T_{_{\mathrm{B}}}$	°C	120
Primary conductor temperature	$U_{\scriptscriptstyle{ESD}}$	kV	2

Stresses above these ratings may cause permanent damage. Exposure to absolute maximum ratings for extended periods may degrade reliability.

## **UL 508: Ratings and assumptions of certification**

File # E189713 Volume: 2 Section: 5

#### **Standards**

- CSA C22.2 NO. 14-10 INDUSTRIAL CONTROL EQUIPMENT Edition 12
- UL 508 STANDARD FOR INDUSTRIAL CONTROL EQUIPMENT Edition 17

#### **Ratings**

Parameter	Symbol	Unit	Value
Primary involved potential		V AC/DC	600
Max surrounding air temperature	$T_{A}$	°C	105
Primary current	$I_{\scriptscriptstyle{ m P}}$	А	According to series primary current
Secondary supply voltage	U <sub>c</sub>	V DC	5
Output voltage	$V_{ m out}$	V	0 to 5

#### **Conditions of acceptability**

- 1 These devices have been evaluated for overvoltage category III and for use in pollution degree 2 environment.
- 2 A suitable enclosure shall be provided in the end-use application.
- 3 The terminals have not been evaluated for field wiring.
- 4 These devices are intended to be mounted on a printed wiring board of end use equipment. The suitability of the connections (including spacings) shall be determined in the end-use application.
- 5 Primary terminals shall not be straightened since assembly of housing case depends upon bending of the terminals.
- 6 Any surface of polymeric housing have not been evaluated as insulating barrier.
- 7 Low voltage control circuit shall be supplied by an isolating source (such as a transformer, optical isolator, limiting impedance or electro-mechanical relay).
- 10 The jumper installed within the primary hole is only intended for fixing the sensor and not for carrying the primary current.

#### Marking

Only those products bearing the UR Mark should be considered to be Listed or Recognized and covered under UL's Follow-Up Service. Always look for the Mark on the product.

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## **Insulation coordination**

Parameter	Symbol	Unit	Value	Comment
RMS voltage for AC insulation test 50/60 Hz/1 min	$U_{\rm d}$	kV	4.3	
Impulse withstand voltage 1.2/50 µs	Û <sub>w</sub>	kV	8	
Partial discharge test voltage (adjusted $q_{\rm m}$ < 10 pC)	$U_{\rm t}$	V	> 1170	Busbar / Secondary + jumpers
Clearance (pri sec.)	d <sub>CI</sub>	mm	> 8	Shortest distance through air
Creepage distance (pri sec.)	d <sub>Cp</sub>	mm	> 8	Shortest path along device body
Clearance (pri sec.)	-	mm	> 8	When mounted on PCB with recommended layout
Case material	-	-	V0 according to UL 94	
Comparative tracking index	CTI		600	
Application example	-	-	600 V CAT III PD2	Reinforced insulation according to IEC 61800-5-1
Application example	-	-	1000 V CAT III PD2	Basic insulation according to IEC 61800-5-1

## **Environmental and mechanical characteristics**

Parameter	Symbol	Unit	Min	Тур	Max	Comment
Ambient operating temperature	$T_{A}$	°C	-40		105	
Ambient storage temperature	$T_{\rm s}$	°C	-40		105	
Mass	m	g		34		



#### Electrical data HO 60-P/SP33-1106

At  $T_{\rm A}$  = 25 °C,  $U_{\rm C}$  = +3.3 V,  $R_{\rm L}$  = 10 k $\Omega$  unless otherwise noted (see Min, Max, typ. definition paragraph in page 12).

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Parameter	Symbol	Unit	Min	Тур	Max	Comment
Primary nominal RMS current	$I_{PN}$	А		60		
Primary current, measuring range	$I_{\scriptscriptstyle{PM}}$	А	-150		150	
Number of primary turns	$N_{_{\mathrm{P}}}$	-		1		See application information
Supply voltage	$U_{\rm c}$	V	3.14	3.3	3.46	
Current consumption	$I_{\scriptscriptstyle  m C}$	mA		19	25	
Reference voltage (output)	$V_{\rm ref}$	V	1.63	1.65	1.67	Internal reference
Reference voltage (input)	$V_{\rm ref}$	V	0.5		1.7	External reference
Output voltage range @ $I_{\scriptscriptstyle \mathrm{PM}}$	V <sub>out</sub> - V <sub>ref</sub>	V	-1.15		1.15	Over operating temperature range
V <sub>ref</sub> output resistance	$R_{\text{ref}}$	Ω	130	200	300	Series
V <sub>out</sub> output resistance	$R_{\text{out}}$	Ω		2	5	Series
Allowed capacitive load	$C_{\scriptscriptstyle L}$	nF	0		6	
Overcurrent detection output on resistance	R <sub>on</sub>	Ω	70	95	150	Open drain, active low Over operating temperature range
Overcurrent detection hold	t <sub>hold</sub>	ms	0.7	1	1.4	Additional time after threshold has released
EEPROM control	$V_{ m out}$	mV	0		50	V <sub>out</sub> forced to GND when EEPROM in an error state <sup>1)</sup>
Electrical offset voltage @ $I_{\rm p}$ = 0 A	V <sub>OE</sub>	mV	-5		5	$V_{\text{out}} - V_{\text{ref}} @ V_{\text{ref}} = 1.65 \text{ V}$
Electrical offset current Referred to primary	$I_{\mathrm{OE}}$	А	-0.652		0.652	
Temperature coefficient of $V_{\text{ref}}$	TCV <sub>ref</sub>	ppm/K	-170		170	−40 °C 105 °C
Temperature coefficient of $V_{\scriptscriptstyle{\mathrm{OE}}}$	TCV <sub>OE</sub>	mV/K	-0.075		0.075	−40 °C 105 °C
Offset drift referred to primary $\textcircled{a}$ $I_p = 0 \text{ A}$	TCI <sub>OE</sub>	mA/K	-9.78		9.78	−40 °C 105 °C
Theoretical sensitivity	$G_{th}$	mV/A		7.67		460 mV @ $I_{\rm PN}$
Sensitivity error @ $I_{\rm PN}$	$\boldsymbol{\varepsilon}_{_{\mathrm{G}}}$	%	-0.5		0.5	Factory adjustment (straight bus-bar)
Temperature coefficient of G	TCG	ppm/K	-350		350	−40 °C 105 °C
Linearity error 0 $\dots$ $I_{PN}$	$arepsilon_{\!\scriptscriptstyle \perp}$	% of $I_{\scriptscriptstyle { m PN}}$	-0.75		0.75	
Linearity error 0 $\dots$ $I_{\rm PM}$	$arepsilon_{\!\scriptscriptstyle \perp}$	% of $I_{\scriptscriptstyle{\mathrm{PM}}}$	-0.5		0.5	
Magnetic offset current (@ 10 × $I_{\rm PN}$ ) referred to primary	$I_{OM}$	А	-0.92		0.92	One turn
Reaction time @ 10 % of $I_{\rm PN}$	t <sub>ra</sub>	μs			2.5	@ 50 A/µs
Response time @ 90 % of $I_{\rm PN}$	$t_{\rm r}$	μs			3.5	@ 50 A/µs
Frequency bandwidth (-3 dB)	BW	kHz		100		Small signals
Output RMS noise voltage spectral density (100 Hz 100 kHz)	e <sub>no</sub>	μV/√ <del>Hz</del>			5.8	
Output noise voltage (DC 10 kHz) (DC 100 kHz) (DC 1 MHz)	V <sub>no</sub>	mVpp		3.7 8.5 16.6		
Primary current, detection threshold	$I_{ m PTh}$	А	2.63 × I <sub>PN</sub>	2.92 × I <sub>PN</sub>	3.21 × I <sub>PN</sub>	Peak value ±10 %, overcurrent detection OCD
Accuracy @ $I_{\scriptscriptstyle{\mathrm{PN}}}$	Х	$\%$ of $I_{\rm PN}$	-1.25		1.25	
Accuracy @ $I_{PN}$ @ $T_A$ = +105 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-5.35		5.35	See formula note 2)
Accuracy @ $I_{PN}$ @ $T_A$ = +85 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-4.33		4.33	See formula note 2)

Notes: 1) EEPROM in an error state makes the transducer behave like a reverse current saturation. Use of the OCD may help to differentiate the two cases

$$^{2)} \, {\rm Accuracy} \, @ \, T_{\rm A} \, (\% \, {\rm of} \, I_{\rm PN}) = X + (\frac{TCG}{10000} \, \times (T_{\rm A} - 25) + \frac{TCI_{\rm OE}}{1000 \times I_{\rm PN}} \times 100 \times (T_{\rm A} \, - 25)).$$

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#### Electrical data HO 100-P/SP33-1106

At  $T_{\rm A}$  = 25 °C,  $U_{\rm C}$  = +3.3 V,  $R_{\rm L}$  = 10 k $\Omega$  unless otherwise noted (see Min, Max, typ. definition paragraph in page 12).

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Parameter	Symbol	Unit	Min	Тур	Max	Comment
Primary nominal RMS current	$I_{PN}$	А		100		
Primary current, measuring range	$I_{\scriptscriptstyle{PM}}$	А	-250		250	
Number of primary turns	N <sub>P</sub>	-		1		See application information
Supply voltage	U <sub>c</sub>	V	3.14	3.3	3.46	
Current consumption	$I_{\rm C}$	mA		19	25	
Reference voltage (output)	$V_{\rm ref}$	V	1.63	1.65	1.67	Internal reference
Reference voltage (input)	$V_{ref}$	V	0.5		1.7	External reference
Output voltage range @ $I_{\scriptscriptstyle{\mathrm{PM}}}$	V <sub>out</sub> - V <sub>ref</sub>	V	-1.15		1.15	Over operating temperature range
V <sub>ref</sub> output resistance	$R_{\text{ref}}$	Ω	130	200	300	Series
V <sub>out</sub> output resistance	R <sub>out</sub>	Ω		2	5	Series
Allowed capacitive load	$C_{\scriptscriptstyle L}$	nF	0		6	
Overcurrent detection output on resistance	R <sub>on</sub>	Ω	70	95	150	Open drain, active low Over operating temperature range
Overcurrent detection hold	$t_{hold}$	ms	0.7	1	1.4	Additional time after threshold has released
EEPROM control	$V_{ m out}$	mV	0		50	$V_{\rm out}$ forced to GND when EEPROM in an error state <sup>1)</sup>
Electrical offset voltage @ $I_P$ = 0 A	$V_{\text{OE}}$	mV	-5		5	V <sub>out</sub> - V <sub>ref</sub> @ V <sub>ref</sub> = 1.65 V
Electrical offset current Referred to primary	$I_{\mathrm{OE}}$	А	-1.087		1.087	
Temperature coefficient of $V_{\text{ref}}$	TCV <sub>ref</sub>	ppm/K	-170		170	−40 °C 105 °C
Temperature coefficient of $V_{\text{\tiny OE}}$	TCV <sub>OE</sub>	mV/K	-0.075		0.075	−40 °C 105 °C
Offset drift referred to primary $\bigcirc$ $I_P = 0$ A	TCI <sub>OE</sub>	mA/K	-16.3		16.3	−40 °C 105 °C
Theoretical sensitivity	$G_{_{th}}$	mV/A		4.6		460 mV @ $I_{\rm PN}$
Sensitivity error @ $I_{\scriptscriptstyle \mathrm{PN}}$	$\boldsymbol{\varepsilon}_{_{\mathrm{G}}}$	%	-0.5		0.5	Factory adjustment (straight bus bar)
Temperature coefficient of G	TCG	ppm/K	-350		350	−40 °C 105 °C
Linearity error 0 $I_{PN}$	$\mathcal{E}_{L}$	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-0.5		0.5	
Linearity error 0 $I_{\rm PM}$	$\mathcal{E}_{L}$	% of $I_{\scriptscriptstyle{\mathrm{PM}}}$	-0.5		0.5	
Magnetic offset current (@ $10 \times I_{PN}$ ) referred to primary	$I_{OM}$	А	-0.92		0.92	One turn
Reaction time @ 10 % of $I_{\rm PN}$	t <sub>ra</sub>	μs			2.5	@ 50 A/µs
Response time @ 90 % of $I_{\scriptscriptstyle \mathrm{PN}}$	t <sub>r</sub>	μs			3.5	@ 50 A/µs
Frequency bandwidth (-3 dB)	BW	kHz		100		Small signals
Output RMS noise voltage spectral density (100 Hz 100 kHz)	e <sub>no</sub>	µV/√ <del>Hz</del>			4	
Output noise voltage (DC 10 kHz) (DC 100 kHz) (DC 1 MHz)	V <sub>no</sub>	mVpp		2.9 5.7 11.5		
Primary current, detection threshold	$I_{ m PTh}$	А	2.63 × I <sub>PN</sub>	2.92 × I <sub>PN</sub>	3.21 × I <sub>PN</sub>	Peak value ±10 %, overcurrent detection OCD
Accuracy @ $I_{_{\mathrm{PN}}}$	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-1		1	
Accuracy @ $I_{PN}$ @ $T_{A}$ = +105 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-5.1		5.1	See formula note 2)
Accuracy @ $I_{PN}$ @ $T_{A}$ = +85 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-4.08		4.08	See formula note 2)

Notes: 1) EEPROM in an error state makes the transducer behave like a reverse current saturation. Use of the OCD may help to differentiate the two cases 2) Accuracy @  $T_A$  (% of  $I_{PN}$ ) =  $X + (\frac{TCG}{10000} \times (T_A - 25) + \frac{TCI_{OE}}{10000 \times I_{PN}} \times 100 \times (T_A - 25))$ .

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## Electrical data HO 120-P/SP33-1106

At  $T_A$  = 25 °C,  $U_C$  = +3.3 V,  $R_L$  = 10 k $\Omega$  unless otherwise noted (see Min, Max, typ. definition paragraph in page 12).

Parameter	Symbol	Unit	Min	Тур	Max	Comment
Primary nominal RMS current	$I_{PN}$	А		120		
Primary current, measuring range	$I_{\scriptscriptstyle{PM}}$	А	-300		300	
Number of primary turns	N <sub>P</sub>	-	İ	1		See application information
Supply voltage	U <sub>c</sub>	V	3.14	3.3	3.46	
Current consumption	$I_{\scriptscriptstyle  m C}$	mA		19	25	
Reference voltage (output)	$V_{ref}$	V	1.63	1.65	1.67	Internal reference
Reference voltage (input)	$V_{\text{ref}}$	V	0.5		1.7	External reference
Output voltage range @ $I_{\scriptscriptstyle{\mathrm{PM}}}$	V <sub>out</sub> - V <sub>ref</sub>	V	-1.15		1.15	Over operating temperature range
V <sub>ref</sub> output resistance	$R_{\text{ref}}$	Ω	130	200	300	Series
V <sub>out</sub> output resistance	R <sub>out</sub>	Ω		2	5	Series
Allowed capacitive load	C <sub>L</sub>	nF	0		6	
Overcurrent detection output on resistance	$R_{on}$	Ω	70	95	150	Open drain, active low Over operating temperature range
Overcurrent detection hold	$t_{hold}$	ms	0.7	1	1.4	Additional time after threshold has released
EEPROM control	V <sub>out</sub>	mV	0		50	$V_{\rm out}$ forced to GND when EEPROM in an error state $^{\rm 1)}$
Electrical offset voltage @ $I_P$ = 0 A	V <sub>OE</sub>	mV	-5		5	$V_{\text{out}} - V_{\text{ref}} @ V_{\text{ref}} = 1.65 \text{ V}$
Electrical offset current Referred to primary	$I_{\scriptscriptstyle{ extsf{OE}}}$	Α	-1.304		1.304	
Temperature coefficient of $V_{\text{ref}}$	TCV <sub>ref</sub>	ppm/K	-170		170	−40 °C 105 °C
Temperature coefficient of $V_{\text{\tiny OE}}$	TCV <sub>OE</sub>	mV/K	-0.075		0.075	−40 °C 105 °C
Offset drift referred to primary @ $I_p$ = 0 A	TCI <sub>OE</sub>	mA/K	-19.57		19.57	−40 °C 105 °C
Theoretical sensitivity	$G_{th}$	mV/A		3.833		460 mV @ $I_{\scriptscriptstyle \mathrm{PN}}$
Sensitivity error @ $I_{\rm PN}$	ε <sub>G</sub>	%	-0.5		0.5	Factory adjustment (straight bus-bar)
Temperature coefficient of G	TCG	ppm/K	-350		350	−40 °C 105 °C
Linearity error 0 $\dots$ $I_{\rm PN}$	$\mathcal{E}_{_{oldsymbol{oldsymbol{arepsilon}}}$	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-0.5		0.5	
Linearity error 0 $\dots$ $I_{\rm PM}$	$\mathcal{E}_{_{oldsymbol{oldsymbol{arepsilon}}}$	% of $I_{\scriptscriptstyle{\mathrm{PM}}}$	-0.5		0.5	
Magnetic offset current (@ 10 × $I_{\rm PN}$ ) referred to primary	$I_{OM}$	Α	-0.92		0.92	One turn
Reaction time @ 10 % of $I_{\rm PN}$	t <sub>ra</sub>	μs			2.5	@ 50 A/µs
Response time @ 90 % of $I_{\rm PN}$	$t_{\rm r}$	μs			3.5	@ 50 A/µs
Frequency bandwidth (-3 dB)	BW	kHz		100		Small signals
Output RMS noise voltage spectral density (100 Hz 100 kHz)	e <sub>no</sub>	μV/√ <del>Hz</del>			3.6	
Output noise voltage (DC 10 kHz) (DC 100 kHz) (DC 1 MHz)	V <sub>no</sub>	mVpp		2.7 5 10.2		
Primary current, detection threshold	$I_{PTh}$	Α	2.63 × I <sub>PN</sub>	2.92 × I <sub>PN</sub>	3.21 × I <sub>PN</sub>	Peak value ±10 %, overcurrent detection OCD
Accuracy @ $I_{\rm PN}$	X	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-1		1	
Accuracy @ $I_{PN}$ @ $T_A$ = +105 °C	X	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-5.1		5.1	See formula note 2)
Accuracy @ $I_{\rm PN}$ @ $T_{\rm A}$ = +85 °C	X	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-4.08		4.08	See formula note 2)

Notes: 1) EEPROM in an error state makes the transducer behave like a reverse current saturation. Use of the OCD may help to differentiate the two cases

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differentiate the two cases <sup>2)</sup> Accuracy @  $T_A$  (% of  $I_{PN}$ ) = X + ( $\frac{TCG}{10000}$  × ( $T_A$ -25) +  $\frac{TCI_{OE}}{1000 \times I_{PN}}$  × 100 × ( $T_A$  -25)).



#### Electrical data HO 180-P/SP33-1106

At  $T_{\rm A}$  = 25 °C,  $U_{\rm C}$  = +3.3 V,  $R_{\rm L}$  = 10 k $\Omega$  unless otherwise noted (see Min, Max, typ. definition paragraph in page 12).

Parameter	Symbol	Unit	Min	Тур	Max	Comment
Primary nominal RMS current	$I_{PN}$	А		180		
Primary current, measuring range	$I_{\scriptscriptstyle{PM}}$	А	-450		450	
Number of primary turns	N <sub>P</sub>	-		1		See application information
Supply voltage	U <sub>c</sub>	V	3.14	3.3	3.46	
Current consumption	$I_{\text{c}}$	mA		19	25	
Reference voltage (output)	$V_{\text{ref}}$	V	1.63	1.65	1.67	Internal reference
Reference voltage (input)	$V_{\text{ref}}$	V	0.5		1.7	External reference
Output voltage range @ $I_{\scriptscriptstyle{\mathrm{PM}}}$	V <sub>out</sub> - V <sub>ref</sub>	V	-1.15		1.15	Over operating temperature range
V <sub>ref</sub> output resistance	R <sub>ref</sub>	Ω	130	200	300	Series
V <sub>out</sub> output resistance	R <sub>out</sub>	Ω		2	5	Series
Allowed capacitive load	$C_{\scriptscriptstyle L}$	nF	0		6	
Overcurrent detection output on resistance	$R_{on}$	Ω	70	95	150	Open drain, active low Over operating temperature range
Overcurrent detection hold	$t_{hold}$	ms	0.7	1	1.4	Additional time after threshold has released
EEPROM control	$V_{ m out}$	mV	0		50	$V_{\rm out}$ forced to GND when EEPROM in an error state <sup>1)</sup>
Electrical offset voltage @ $I_P$ = 0 A	V <sub>OE</sub>	mV	-5		5	V <sub>out</sub> - V <sub>ref</sub> @ V <sub>ref</sub> = 1.65 V
Electrical offset current Referred to primary	$I_{\scriptscriptstyle{ m OE}}$	А	-1.956		1.956	
Temperature coefficient of $V_{\text{ref}}$	TCV <sub>ref</sub>	ppm/K	-170		170	−40 °C 105 °C
Temperature coefficient of $V_{\text{\tiny OE}}$	TCV <sub>OE</sub>	mV/K	-0.075		0.075	−40 °C 105 °C
Offset drift referred to primary $\textcircled{0} I_{P} = 0 \text{ A}$	TCI <sub>OE</sub>	mA/K	-29.35		29.35	−40 °C 105 °C
Theoretical sensitivity	$G_{th}$	mV/A		2.556		460 mV @ I <sub>PN</sub>
Sensitivity error @ $I_{\rm PN}$	$\boldsymbol{\mathcal{E}}_{G}$	%	-0.5		0.5	Factory adjustment (straight bus-bar)
Temperature coefficient of G	TCG	ppm/K	-350		350	−40 °C 105 °C
Linearity error 0 $\dots$ $I_{\rm PN}$	$\mathcal{E}_{L}$	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-0.5		0.5	
Linearity error 0 $\dots$ $I_{\rm PM}$	$\mathcal{E}_{oldsymbol{oldsymbol{arepsilon}}}$	% of $I_{\scriptscriptstyle{\mathrm{PM}}}$	-0.5		0.5	
Magnetic offset current (@ 10 × $I_{\rm PN}$ ) referred to primary	$I_{\scriptscriptstyle{OM}}$	А	-0.92		0.92	One turn
Reaction time @ 10 % of $I_{\scriptscriptstyle \mathrm{PN}}$	t <sub>ra</sub>	μs			2.5	@ 50 A/µs
Response time @ 90 % of $I_{\rm PN}$	t <sub>r</sub>	μs			3.5	@ 50 A/µs
Frequency bandwidth (-3 dB)	BW	kHz		100		Small signals
Output RMS noise voltage spectral density (100 Hz 100 kHz)	e <sub>no</sub>	μV/√ <del>Hz</del>			2.8	
Output noise voltage (DC 10 kHz) (DC 100 kHz) (DC 1 MHz)	V <sub>no</sub>	mVpp		2.4 3.9 8.1		
Primary current, detection threshold	$I_{\scriptscriptstyle{PTh}}$	А	2.63 × I <sub>PN</sub>	2.92 × I <sub>PN</sub>	3.21 × I <sub>PN</sub>	Peak value ±10 %, overcurrent detection OCD
Accuracy @ $I_{\rm PN}$	X	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-1		1	
Accuracy @ $I_{PN}$ @ $T_A$ = +105 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-5.1		5.1	See formula note 2)
Accuracy @ $I_{PN}$ @ $T_A$ = +85 °C	X	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-4.08		4.08	See formula note 2)

Notes: 1) EEPROM in an error state makes the transducer behave like a reverse current saturation. Use of the OCD may help to differentiate the two cases

differentiate the two cases <sup>2</sup> Accuracy @  $T_A$  (% of  $I_{PN}$ ) = X + ( $\frac{TCG}{10000}$  × ( $T_A$  -25) +  $\frac{TCI_{OE}}{1000 \times I_{PN}}$  × 100 × ( $T_A$  -25)).

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#### Electrical data HO 250-P/SP33-1106

At  $T_{\rm A}$  = 25 °C,  $U_{\rm C}$  = +3.3 V,  $R_{\rm L}$  = 10 k $\Omega$  unless otherwise noted (see Min, Max, typ. definition paragraph in page 12).

Parameter	Symbol	Unit	Min	Тур	Max	Comment
Primary nominal RMS current	$I_{PN}$	А		250		
Primary current, measuring range	$I_{\scriptscriptstyle{PM}}$	А	-625		625	
Number of primary turns	N <sub>P</sub>	-		1		See application information
Supply voltage	U <sub>c</sub>	V	3.14	3.3	3.46	
Current consumption	$I_{\rm c}$	mA		19	25	
Reference voltage (output)	$V_{\text{ref}}$	V	1.63	1.65	1.67	Internal reference
Reference voltage (input)	$V_{\text{ref}}$	V	0.5		1.7	External reference
Output voltage range @ $I_{\scriptscriptstyle{\mathrm{PM}}}$	V <sub>out</sub> - V <sub>ref</sub>	V	-1.15		1.15	Over operating temperature range
V <sub>ref</sub> output resistance	R <sub>ref</sub>	Ω	130	200	300	Series
V <sub>out</sub> output resistance	R <sub>out</sub>	Ω		2	5	Series
Allowed capacitive load	C <sub>L</sub>	nF	0		6	
Overcurrent detection output on resistance	R <sub>on</sub>	Ω	70	95	150	Open drain, active low Over operating temperature range
Overcurrent detection hold	$t_{hold}$	ms	0.7	1	1.4	Additional time after threshold has released
EEPROM control	$V_{ m out}$	mV	0		50	$V_{\rm out}$ forced to GND when EEPROM in an error state $^{\rm 1)}$
Electrical offset voltage @ $I_{\rm P}$ = 0 A	V <sub>OE</sub>	mV	-5		5	$V_{\text{out}} - V_{\text{ref}} @ V_{\text{ref}} = 1.65 \text{ V}$
Electrical offset current Referred to primary	$I_{\mathrm{OE}}$	А	-2.717		2.717	
Temperature coefficient of $V_{\text{ref}}$	TCV <sub>ref</sub>	ppm/K	-170		170	−40 °C 105 °C
Temperature coefficient of $V_{\text{\tiny OE}}$	TCV <sub>OE</sub>	mV/K	-0.075		0.075	−40 °C 105 °C
Offset drift referred to primary $\bigcirc$ $I_p = 0$ A	TCI <sub>OE</sub>	mA/K	-40.76		40.76	−40 °C 105 °C
Theoretical sensitivity	G <sub>th</sub>	mV/A		1.84		460 mV @ I <sub>PN</sub>
Sensitivity error @ $I_{\rm PN}$	$\varepsilon_{_{\mathrm{G}}}$	%	-0.5		0.5	Factory adjustment (straight bus-bar)
Temperature coefficient of G	TCG	ppm/K	-350		350	−40 °C 105 °C
Linearity error 0 $I_{\rm PN}$	$\mathcal{E}_{L}$	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-0.5		0.5	
Linearity error 0 $I_{\rm PM}$	$\mathcal{E}_{L}$	% of $I_{\scriptscriptstyle{\mathrm{PM}}}$	-0.5		0.5	
Magnetic offset current (@ 10 × $I_{\rm PN}$ ) referred to primary	$I_{OM}$	А	-0.92		0.92	One turn
Reaction time @ 10 % of $I_{\rm PN}$	t <sub>ra</sub>	μs			2.5	@ 50 A/µs
Response time @ 90 % of $I_{\rm PN}$	t <sub>r</sub>	μs			3.5	@ 50 A/µs
Frequency bandwidth (-3 dB)	BW	kHz	ĺ	100		Small signals
Output RMS noise voltage spectral density (100 Hz 100 kHz)	e <sub>no</sub>	μV/√ <del>Hz</del>			2.9	
Output noise voltage (DC 10 kHz) (DC 100 kHz) (DC 1 MHz)	V <sub>no</sub>	mVpp		2.6 4.7 8.2		
Primary current, detection threshold	$I_{ m PTh}$	А	2.63 × I <sub>PN</sub>	2.92 × I <sub>PN</sub>	3.21 × I <sub>PN</sub>	Peak value ±10 %, overcurrent detection OCD
Accuracy @ $I_{_{\mathrm{PN}}}$	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-1		1	
Accuracy @ $I_{PN}$ @ $T_A$ = +105 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-5.1		5.1	See formula note 2)
Accuracy @ $I_{PN}$ @ $T_{A}$ = +85 °C	Х	% of $I_{\scriptscriptstyle{\mathrm{PN}}}$	-4.08		4.08	See formula note 2)

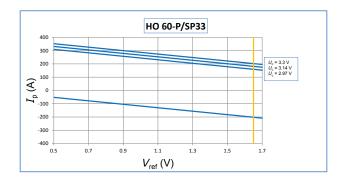
Notes: 1) EEPROM in an error state makes the transducer behave like a reverse current saturation. Use of the OCD may help to

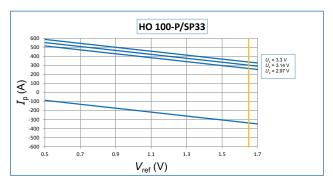
differentiate the two cases <sup>2)</sup> Accuracy @  $T_A$  (% of  $I_{PN}$ ) = X + ( $\frac{TCG}{10000}$  × ( $T_A$  -25) +  $\frac{TCI_{OE}}{1000 \times I_{PN}}$  × 100 × ( $T_A$  -25)).

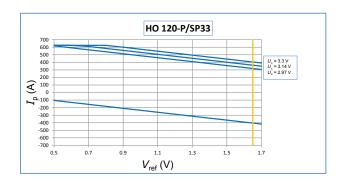
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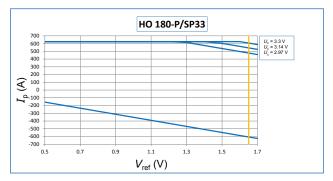


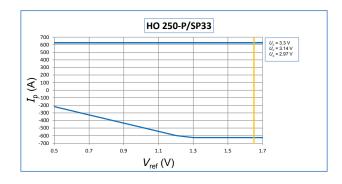
## HO-P/SP33 series, measuring range versus external reference voltage







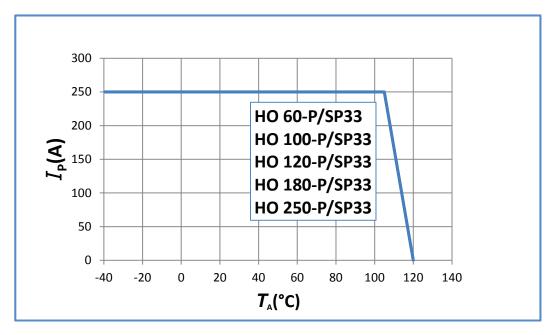






#### **Maximum continuous DC current**

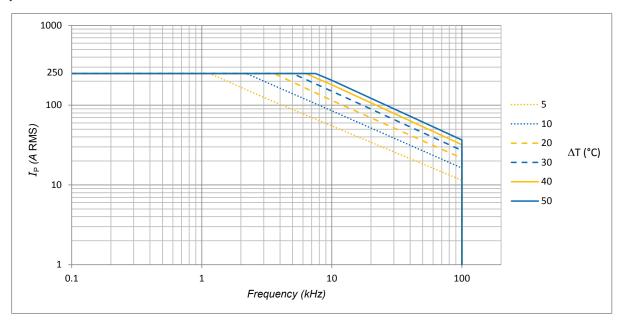
For all ranges:



Important notice: whatever the usage and/or application, the transducer primary bar / jumper temperature shall not go above the maximum rating of 120 °C as stated in page 2 of this datasheet.

#### Frequency derating versus primary current and core temperature increase $\Delta T$ (°C)

Primary current in A RMS is sine wave.



Example:

Primary current ripple (sine wave): 50 A RMS

Ripple frequency: 20 kHz

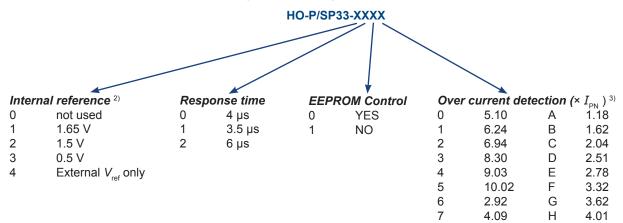
- the core temperature increase is 10  $^{\circ}\text{C}$ 

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#### HO-P/SP33 series: name and codification

HO family products may be ordered **on request** 1) with a dedicated setting of the parameters as described below (standard products are delivered with the setting 1106 according to the table).



Standard products are:

- HO 60-P/SP33-1106
- HO 100-P/SP33-1106
- HO 120-P/SP33-1106
- HO 180-P/SP33-1106
- HO 250-P/SP33-1106

Notes: 1) For dedicated settings, minimum quantities apply, please contact your local LEM support

 $^{2)}$   $V_{\rm ref}$  electrical data

V		$V_{\rm ref}$ (V)	TCV <sub>ref</sub> (	ppm/K)	
parameter	min	typ	max	min	max
0	-	-	-	-	-
1	1.63	1.65	1.67	-170	170
2	1.48	1.5	1.52	-170	170
3	0.49	0.5	0.51	-250	250

 $<sup>^{\</sup>rm 3)}$  OCD (×  $I_{\rm PN})$  correction table versus range and temperature. All other values or empty cells: no change

	HO-P/SP33-110x						
OCD	$I_{_{\mathrm{P}}}$	(A) all te	mperature	s			
Parameter	100	120	180	250			
Α							
В							
С							
D							
E							
6							
F							
G							
Н							
7							
0				6.90			
1			6.39	-			
2			9.02	-			
3			-	-			
4			-	-			
5		11.98	-	-			

Tolerance on OCD value				
±20 %				
±15 %				
±10 %	No change			
-	Do not use			

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#### **Application information**

 HOxx-P series is designed to be used with a bus-bar or a cable <sup>1)</sup> to carry the current through the aperture with a maximum cross-section of 15 × 8 mm.

The 2 jumpers should be used as mechanical fixation on the PCBA and must be kept in open circuit.

#### Definition of typical, minimum and maximum values

Minimum and maximum values for specified limiting and safety conditions have to be understood as such as well as values shown in "typical" graphs.

On the other hand, measured values are part of a statistical distribution that can be specified by an interval with upper and lower limits and a probability for measured values to lie within this interval.

Unless otherwise stated (e.g. "100 % tested"), the LEM definition for such intervals designated with "min" and "max" is that the probability for values of samples to lie in this interval is 99.73 %.

For a normal (Gaussian) distribution, this corresponds to an interval between –3 sigma and +3 sigma. If "typical" values are not obviously mean or average values, those values are defined to delimit intervals with a probability of 68.27 %, corresponding to an interval between –sigma and +sigma for a normal distribution.

Typical, maximal and minimal values are determined during the initial characterization of the product.

#### Remark

Installation of the transducer must be done unless otherwise specified on the datasheet, according to LEM Transducer Generic Mounting Rules. Please refer to LEM document N°ANE120504 available on our Web site: **Products/Product Documentation** 

#### **Safety**

This transducer must be used in limited-energy secondary circuits.



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



Caution, risk of electrical shock.

When operating the transducer, certain parts of the module can carry hazardous voltage (e.g. primary bus bar, power supply). Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a build-in device, whose conducting parts must be inaccessible after installation.

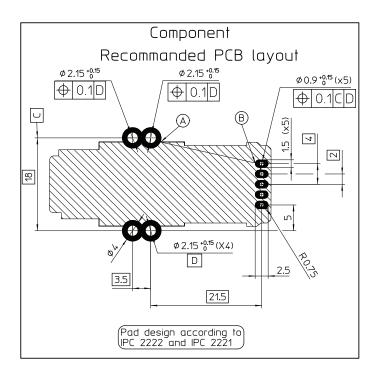
A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

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#### **PCB Footprint in mm**



# **Assembly on PCB**

• Recommended PCB hole diameter

Maximum PCB thickness

Wave soldering profile No clean process only 2.15 mm for primary pin0.9 mm for secondary pin

2.4 mm

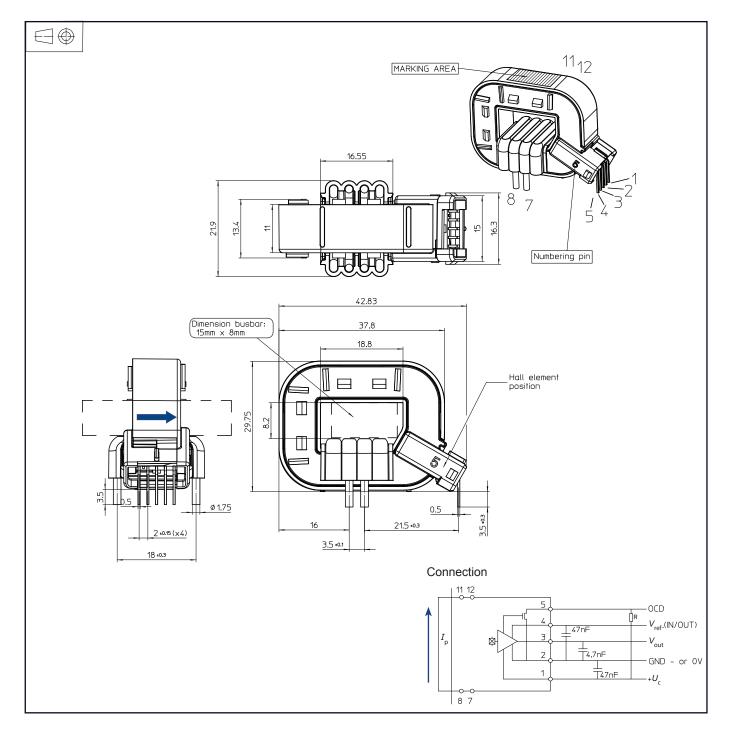
maximum 260 °C, 10 s

# Insulation distance (nominal values):

	$d_{ extsf{Cp}}$	$d_{\scriptscriptstyle{ extsf{CI}}}$
On PCB: A - B	18.85 mm	-
Between jumper and secondary pin	21.1 mm	20.9 mm
Between primary busbar and secondary pin	14.6 mm	-
Between primary busbar and jumper	-	8 mm
Between primary busbar and core	-	11.34 mm
Between core and secondary terminal	-	1.18 mm



## Dimensions HO-P/SP33 series (mm, general linear tolerance ±0.3 mm)



#### Remark:

•  $V_{\text{OUT}}$  is positive with respect to  $V_{\text{ref}}$  when positive  $I_{\text{P}}$  flows in direction of the arrow shown on the drawing above.

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# 单击下面可查看定价,库存,交付和生命周期等信息

# >>LEM(莱姆)